

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

5/19
6-6-02

Applicants: MURATA, et al.

Filed: December 3, 2001

For: SEMICONDUCTOR INTEGRATED CIRCUIT DEVICE
HAVING SWITCHING MISFET AND CAPACITOR
ELEMENT AND METHOD OF PRODUCING THE SAME,
INCLUDING WIRING THEREFOR AND METHOD OF
PRODUCING SUCH WIRING

PRELIMINARY AMENDMENT

Assistant Commissioner for Patents
Washington, D.C. 20231

December 3, 2001

Sir:

Please amend the above-identified application, prior to examination thereof,
as follows:

IN THE SPECIFICATION

Please delete the paragraph beginning at page 1, line 1, of the specification,
and substitute therefor the following new paragraph:

--This application is a Continuation application of application Serial No.

09/915,590, filed July 27, 2001, which is a Continuation application of application
Serial No. 09/317,999, filed May 25, 1999, now U.S. Patent No. 6,281,071, which